

RJK03N1DPA

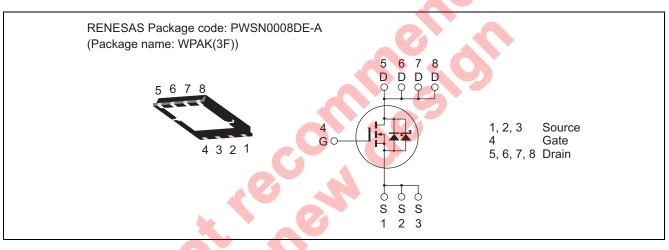
30V, 45A, 3.0mΩmax. Built in SBD N Channel Power MOS FET High Speed Power Switching

R07DS0782EJ0200 Rev.2.00 Feb 12, 2013

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

		$(Ta = 25^{\circ}C)$		
Item	Symbol	Ratings	Unit	
Drain to source voltage	V _{DSS}	30	V	
Gate to source voltage	V _{GSS}	±12	V	
Drain current	I _D	45	A	
Drain peak current	Note1 I _{D(pulse)}	180	A	
Body-drain diode reverse drain current	I _{DR}	45	A	
Avalanche current	I _{AP} Note 2	17	A	
Avalanche energy	E _{AS} Note 2	29	mJ	
Channel dissipation	Pch Note3	40	W	
Channel to case thermal impedance	θch-c ^{Note3}	3.13	°C/W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	۵°C	

Notes: 1. PW \leq 10 $\mu s,\,duty\,cycle \leq$ 1%

- 2. Value at Tch = 25°C, Rg \geq 50 Ω
- 3. Tc = 25°C

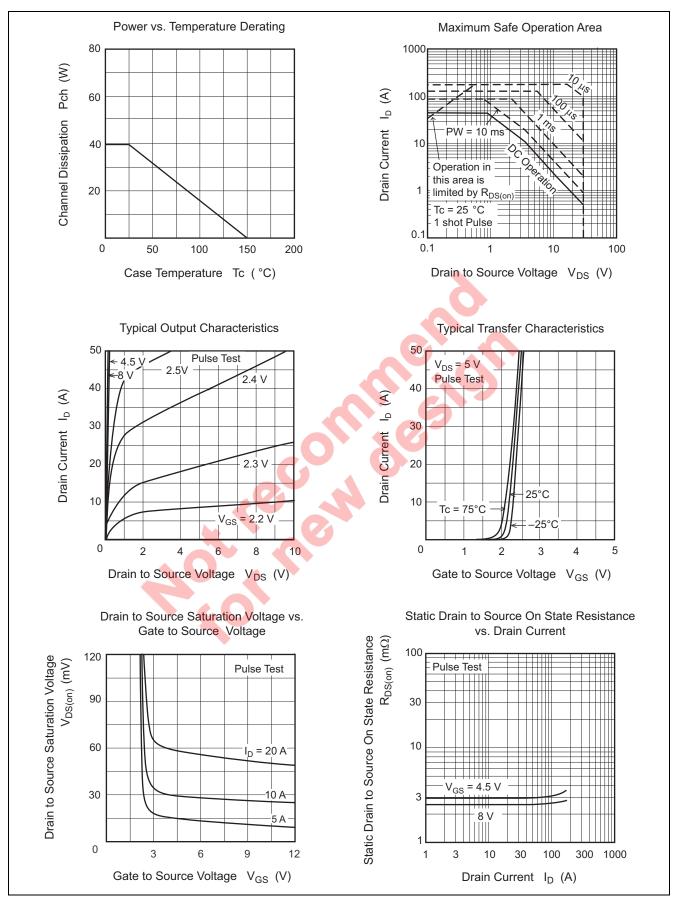


Electrical Characteristics

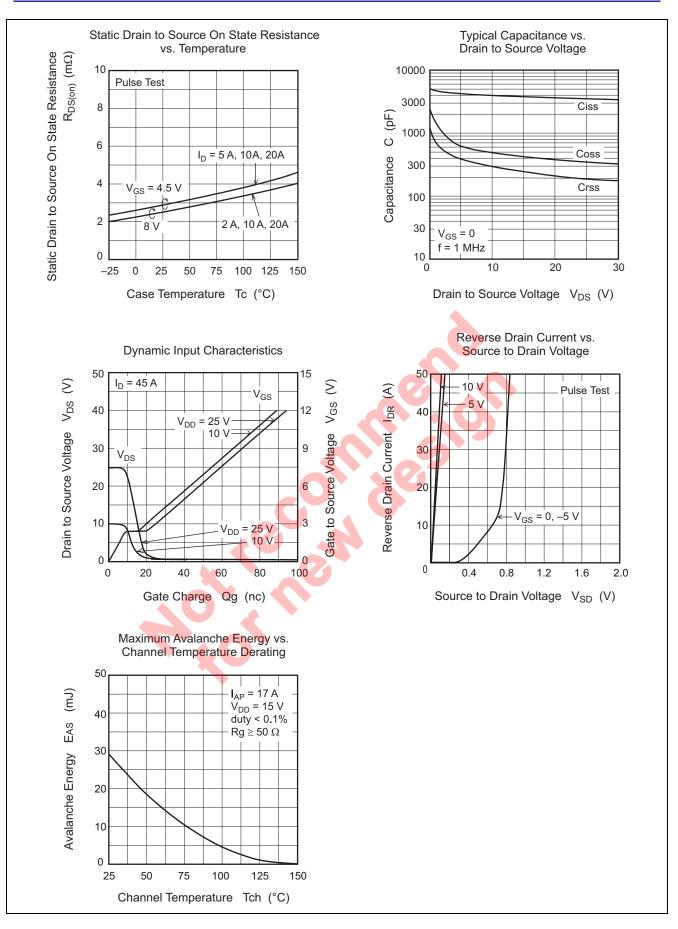
						$(Ta = 25^{\circ}C)$		
Item	Symbol	Min	Тур	Max	Unit	Test Conditions		
Drain to source breakdown voltage	V _{(BR)DSS}	30	—	—	V	I_{D} = 10 mA, V_{GS} = 0		
Gate to source leak current	I _{GSS}	—	_	± 0.5	μA	V_{GS} = ±12 V, V_{DS} = 0		
Zero gate voltage drain current	I _{DSS}	—	_	1	mA	V_{DS} = 24 V, V_{GS} = 0		
Gate to source cutoff voltage	V _{GS(off)}	1.2	—	2.5	V	V_{DS} = 10 V, I _D = 1 mA		
Static drain to source on state	R _{DS(on)}	—	2.5	3.0	mΩ	I_D = 22.5A, V_{GS} = 8.0 V ^{Note4}		
resistance	R _{DS(on)}	—	2.9	3.7	mΩ	I_D = 22.5A, V_{GS} = 4.5 V ^{Note4}		
Forward transfer admittance	y _{fs}	—	127	—	S	I_D = 22.5A, V_{DS} = 5 V ^{Note4}		
Input capacitance	Ciss	—	4000	5600	pF	V _{DS} = 10 V		
Output capacitance	Coss	—	480		pF	V _{GS} = 0		
Reverse transfer capacitance	Crss	—	295	—	pF	f = 1 MHz		
Gate Resistance	Rg	_	1.5	3.0	Ω			
Total gate charge	Qg		31.5		nC nC	V _{DD} = 10 V		
Gate to source charge	Qgs		9.0			V _{GS} = 4.5 V		
Gate to drain charge	Qgd		8.3		nC	I _D = 45 A		
Turn-on delay time	t _{d(on)}		8.7	_	ns	V _{GS} = 8 V, I _D = 22.5 A		
Rise time	tr	_	4.8		ns	$V_{DD} \cong 10 V$		
Turn-off delay time	t _{d(off)}	_	76		ns	$R_L = 0.44\Omega$		
Fall time	t _f	_	20		ns	Rg = 4.7 Ω		
Body–drain diode forward voltage	V _{DF}	_	0.41	—	V	$I_F = 2 A, V_{GS} = 0^{Note4}$		
Body–drain diode reverse recovery	t _{rr}		8.6	_	ns	I _F =45 A, V _{GS} = 0		
time				6		di _F / dt = 500 A/ µs		
time di _F / dt = 500 A/ μs								

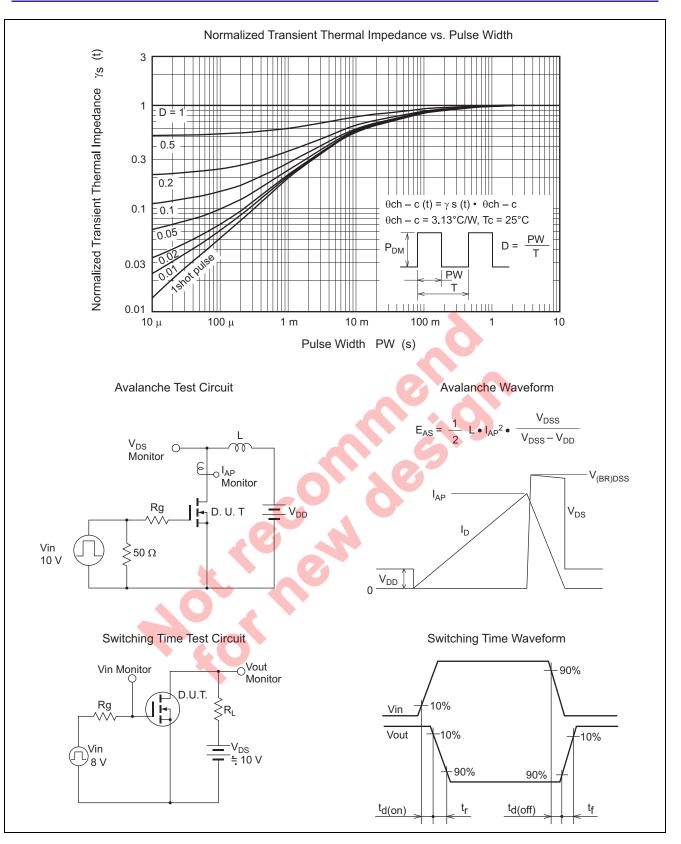


Main Characteristics

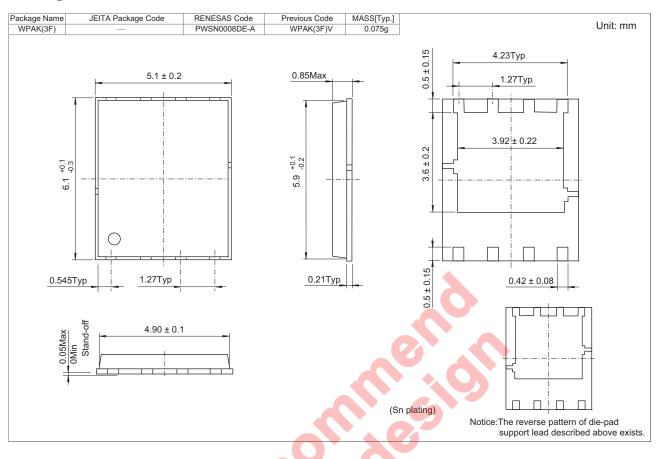








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK03N1DPA-00-J5A	3000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".

Rec.



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